

350mA 12kV HIGH VOLTAGE DIODES

Finds use in applications such as Monitors, Static electricity dust collectors, Laser power supplies, ect..

Features

- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

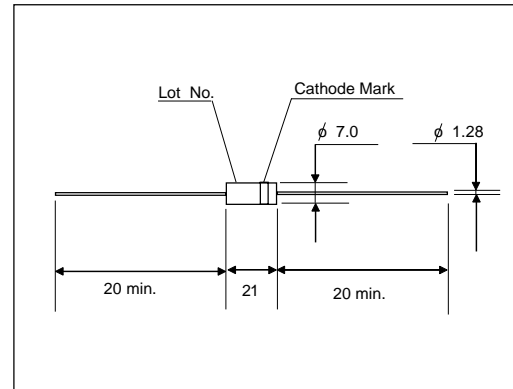
Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

Maximum Ratings and Characteristics

- Absolute Maximum Ratings

Outline Drawings : mm



Cathode Mark

Type	Mark
ESJC13-12	

Items	Symbols	Condition	ESJC13-12	Units
Repetitive Peak Reverse Voltage	V_{RRM}		12	kV
Average Output Current	I_o	Ta=25°C, Resistive Load	350	mA
Surge Current	I_{FSM}		30	A _{peak}
Junction Temperature	T _J		125	°C
Allowable Operation Case Temperature	T _c		125	°C
Storage Temperature	T _{stg}		-40 to +130	°C

- Electrical Characteristics (Ta=25°C Unless otherwise specified)

Items	Symbols	Conditions	ESJC13-09	Units
Maximum Forward Voltage Drop	V_F	at 25°C, $I_F = I_{F(AV)}$	11	V
Maximum Reverse Current	IR1	at 25°C, $V_R = V_{RRM}$	5.0	uA
	IR2	at 100°C, $V_R = V_{RRM}$	50	uA
Maximum Reverse Recovery Time	T _{rr}	at 25°C	--	nS
Junction Capacitance	C _j	at 25°C, $V_R = 0V, f = 1MHz$	--	pF